

## Excellent Integrated System Limited

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[IXYS Corporation](#)

[IXGP12N100AU1](#)

For any questions, you can email us directly:

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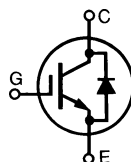
# IXYS

## IGBT

Combi Pack

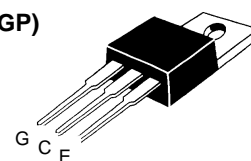
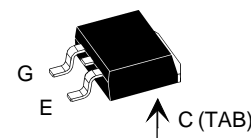
**IXGA/IXGP12N100U1**  
**IXGA/IXGP12N100AU1**

$V_{CES}$	$I_{C25}$	$V_{CE(sat)}$
1000 V	24 A	3.5 V
1000 V	24 A	4.0 V



Preliminary Data Sheet

Symbol	Test Conditions	Maximum Ratings	
$V_{CES}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	1000	V
$V_{CGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GE} = 1\text{ M}\Omega$	1000	V
$V_{GES}$	Continuous	$\pm 20$	V
$V_{GEM}$	Transient	$\pm 30$	V
$I_{C25}$	$T_C = 25^\circ\text{C}$	24	A
$I_{C90}$	$T_C = 90^\circ\text{C}$	12	A
$I_{CM}$	$T_C = 25^\circ\text{C}$ , 1 ms	48	A
<b>SSOA</b>	$V_{GE} = 15\text{ V}$ , $T_{VJ} = 125^\circ\text{C}$ , $R_G = 150\ \Omega$	$I_{CM} = 24$	A
<b>(RBSOA)</b>	Clamped inductive load, $L = 300\ \mu\text{H}$	@ $0.8 V_{CES}$	
$P_C$	$T_C = 25^\circ\text{C}$	100	W
$T_J$		-55 ... +150	$^\circ\text{C}$
$T_{JM}$		150	$^\circ\text{C}$
$T_{stg}$		-55 ... +150	$^\circ\text{C}$
$M_d$	Mounting torque with screw M3	0.45/4	Nm/lb.in.
	Mounting torque with screw M3.5	0.55/5	Nm/lb.in.
<b>Weight</b>		4	g
Maximum lead temperature for soldering		300	$^\circ\text{C}$
1.6 mm (0.062 in.) from case for 10 s			

**TO-220AB(IXGP)**

**TO-263 AA (IXGA)**

**Features**

- International standard packages JEDEC TO-220AB and TO-263AA
- IGBT with antiparallel FRED in one package
- Second generation HDMOS™ process
- Low  $V_{CE(sat)}$ 
  - for minimum on-state conduction losses
- MOS Gate turn-on
  - drive simplicity
- Fast Recovery Expitaxial Diode (FRED)
  - soft recovery with low  $I_{RM}$

**Applications**

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

**Advantages**

- Easy to mount with one screw
- Space savings (two devices in one package)
- Reduces assembly time and cost
- High power density

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{CES}$	$I_C = 3\text{ mA}$ , $V_{GE} = 0\text{ V}$	1000		V
$V_{GE(th)}$	$I_C = 250\ \mu\text{A}$ , $V_{GE} = V_{GE}$	2.5		V
$I_{CES}$	$V_{CE} = 0.8$ , $V_{CES}$ $V_{GE} = 0\text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$		300 $\mu\text{A}$ 3 mA
$I_{GES}$	$V_{CE} = 0\text{ V}$ , $V_{GE} = \pm 20\text{ V}$			$\pm 100\text{ nA}$
$V_{CE(sat)}$	$I_C = I_{C90}$ , $V_{GE} = 15$	12N100 12N100A		3.5 V 4.0 V

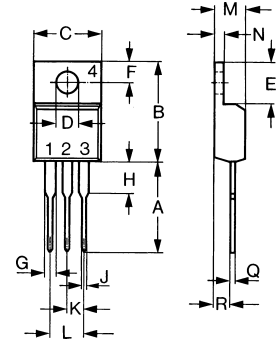


**IXGA12N100U1**  
**IXGA12N100AU1**

**IXGP12N100U1**  
**IXGP12N100AU1**

Symbol	Test Conditions	Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$I_C = I_{C90}; V_{CE} = 10 V,$ Pulse test, $t \leq 300 \mu s,$ duty cycle $\leq 2 \%$	6	10	S
$Q_g$	$I_C = I_{C90}; V_{GE} = 15 V, V_{CE} = 0.5 V_{CES}$		65	90 nC
$Q_{ge}$			8	20 nC
$Q_{gc}$			24	45 nC
$t_{d(on)}$	<b>Inductive load, <math>T_J = 25^\circ C</math></b> $I_C = I_{C90}, V_{GE} = 15 V, L = 300 \mu H$ $V_{CE} = 800 V, R_G = R_{off} = 120 \Omega$ Remarks: Switching times may increase for $V_{CE} (Clamp) > 0.8 V_{CES},$ higher $T_J$ or increased $R_G$		100	ns
$t_{ri}$			200	ns
$t_{d(off)}$			850	1000 ns
$t_{fi}$			500	700 ns
$E_{off}$			800	1000 ns
$t_{d(on)}$	<b>Inductive load, <math>T_J = 125^\circ C</math></b> $I_C = I_{C90}, V_{GE} = 15 V, L = 300 \mu H$ $V_{CE} = 800 V, R_G = R_{off} = 120 \Omega$ Remarks: Switching times may increase for $V_{CE} (Clamp) > 0.8 V_{CES},$ higher $T_J$ or increased $R_G$		100	ns
$t_{ri}$			200	ns
$E_{on}$			1.1	mJ
$t_{d(off)}$			900	ns
$t_{fi}$			950	ns
$E_{off}$			1250	ns
$R_{thJC}$			8	mJ
$R_{thCK}$			10	mJ
$R_{thJC}$			1.25	K/W
$R_{thCK}$		0.25		K/W

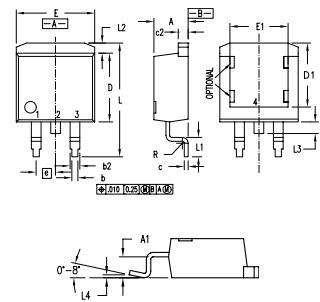
**TO-220 AB (IXGP) Outline**



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.70	13.97	0.500	0.550
B	14.73	16.00	0.580	0.630
C	9.91	10.66	0.390	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.270
F	2.54	3.18	0.100	0.125
G	1.15	1.65	0.045	0.065
H	2.79	5.84	0.110	0.230
J	0.64	1.01	0.025	0.040
K	2.54	BSC	0.100	BSC
M	4.32	4.82	0.170	0.190
N	1.14	1.39	0.045	0.055
Q	0.35	0.56	0.014	0.022
R	2.29	2.79	0.090	0.110

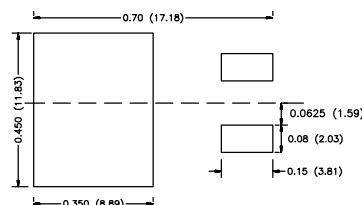
Symbol	Test Conditions	Characteristic Values		
		Min.	Typ.	Max.
$V_F$	$I_F = 8A, V_{GE} = 0 V,$ Pulse test, $t \leq 300 \mu s,$ duty cycle $d \leq 2 \%$			2.75 V
$I_{RM}$	$I_F = I_{C90}, V_{GE} = 0 V, -di_F/dt = 100 A/\mu s$		6.5	A
$t_{rr}$	$V_R = 100 V, T_J = 125^\circ C$ $I_F = 1 A, -di/dt = 50 A/\mu s, V_R = 30 V T_J = 25^\circ C$		140	ns
$R_{thJC}$			50	60 ns
$R_{thJC}$			2.5	K/W

**TO-263 AA (IXGA) Outline**



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.06	4.83	.160	.190
A1	2.03	2.79	.080	.110
b	0.51	0.99	.020	.039
b2	1.14	1.40	.045	.055
c	0.46	0.74	.018	.029
c2	1.14	1.40	.045	.055
D	8.64	9.65	.340	.380
D1	7.11	8.13	.280	.320
E	9.65	10.29	.380	.405
E1	6.86	8.13	.270	.320
e	2.54	BSC	.100	BSC
L	14.61	15.88	.575	.625
L1	2.29	2.79	.090	.110
L2	1.02	1.40	.040	.055
L3	1.27	1.78	.050	.070
L4	0	0.38	0	.015
R	0.46	0.74	.018	.029

**Min. Recommended Footprint**



	<b>IXGA12N100U1</b> <b>IXGA12N100AU1</b>	<b>IXGP12N100U1</b> <b>IXGP12N100AU1</b>
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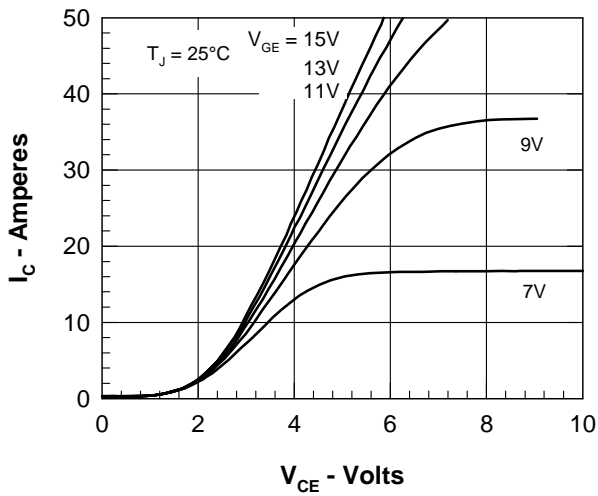


Figure 1. Saturation Voltage Characteristics

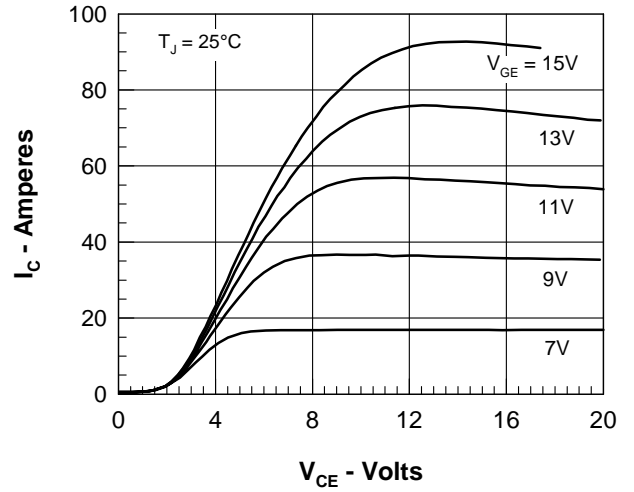


Figure 2. Extended Output Characteristics

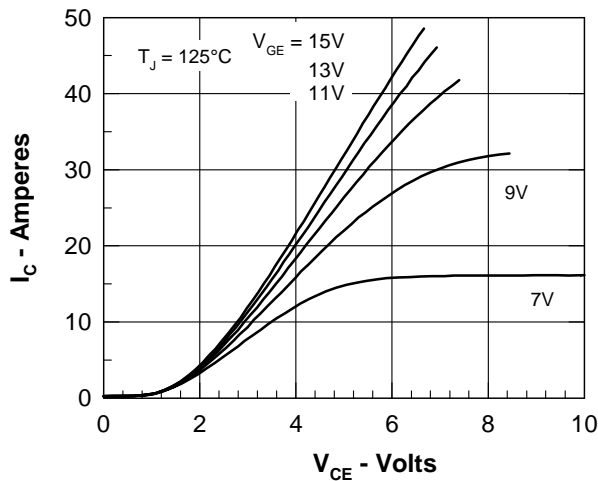


Figure 3. Saturation Voltage Characteristics

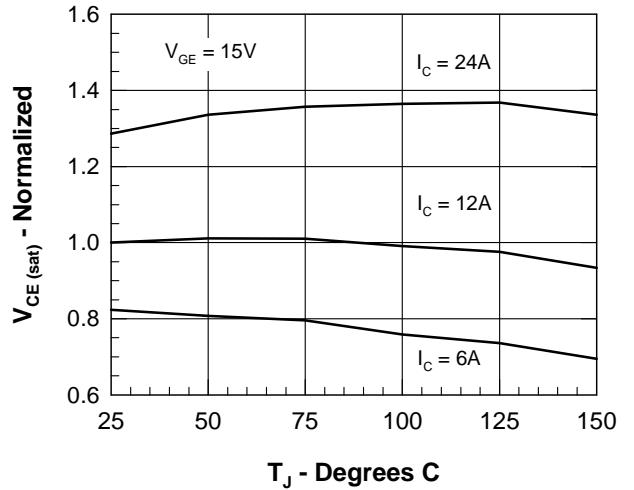


Figure 4. Temperature Dependence of  $V_{CE(sat)}$

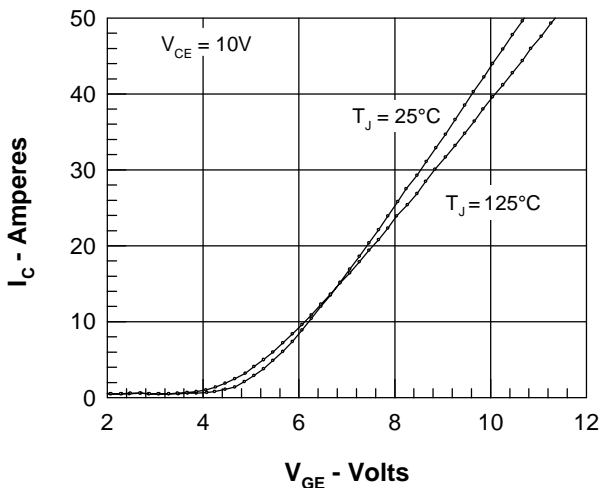


Figure 5. Admittance Curves

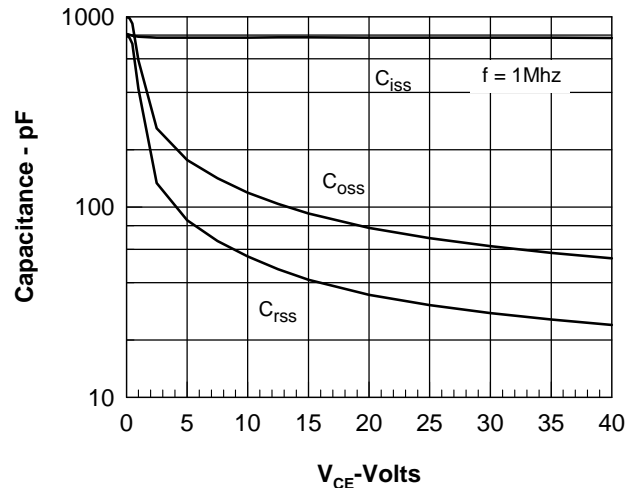


Figure 6. Capacitance Curves



**IXGA12N100U1**  
**IXGA12N100AU1**

**IXGP12N100U1**  
**IXGP12N100AU1**

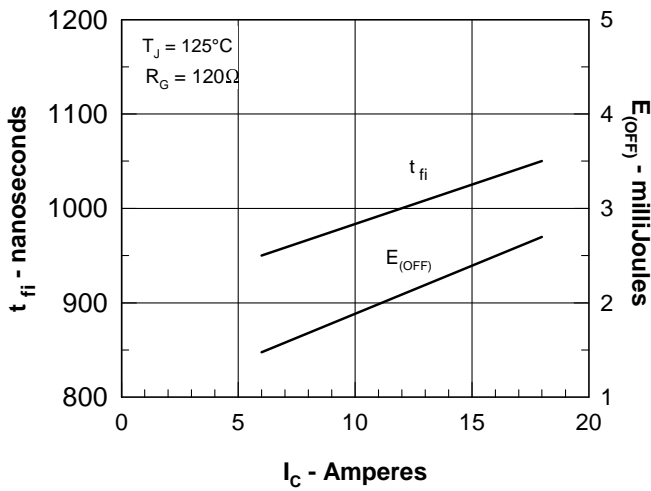


Figure 7. Dependence of  $t_{fi}$  and  $E_{OFF}$  on  $I_C$ .

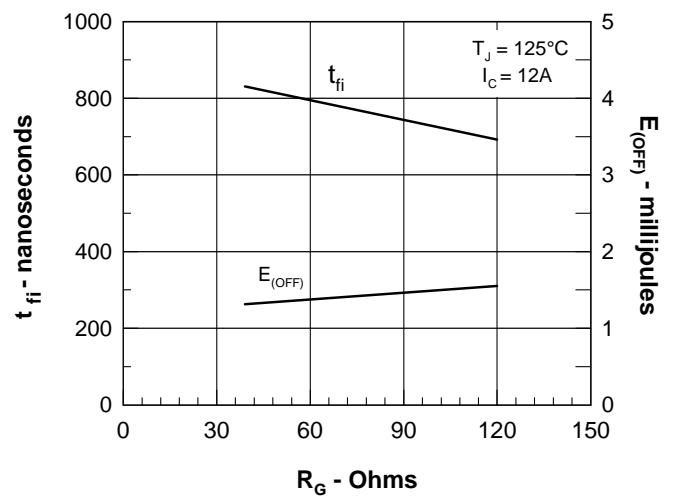


Figure 8. Dependence of  $t_{fi}$  and  $E_{OFF}$  on  $R_G$ .

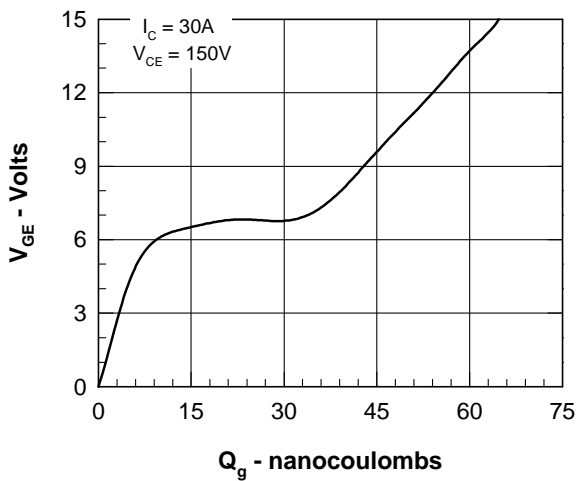


Figure 9. Gate Charge

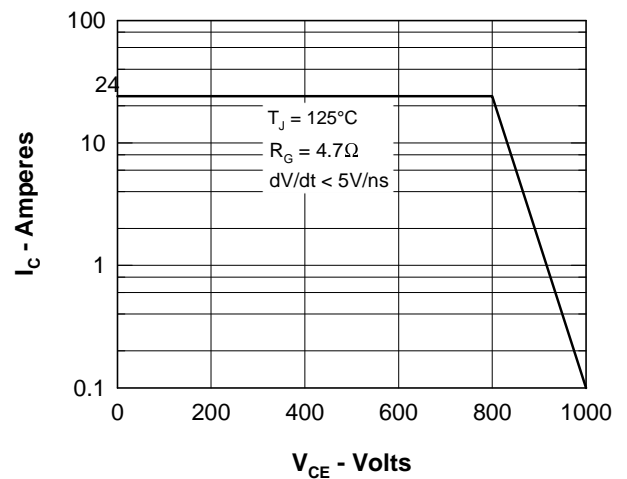


Figure 10. Turn-off Safe Operating Area

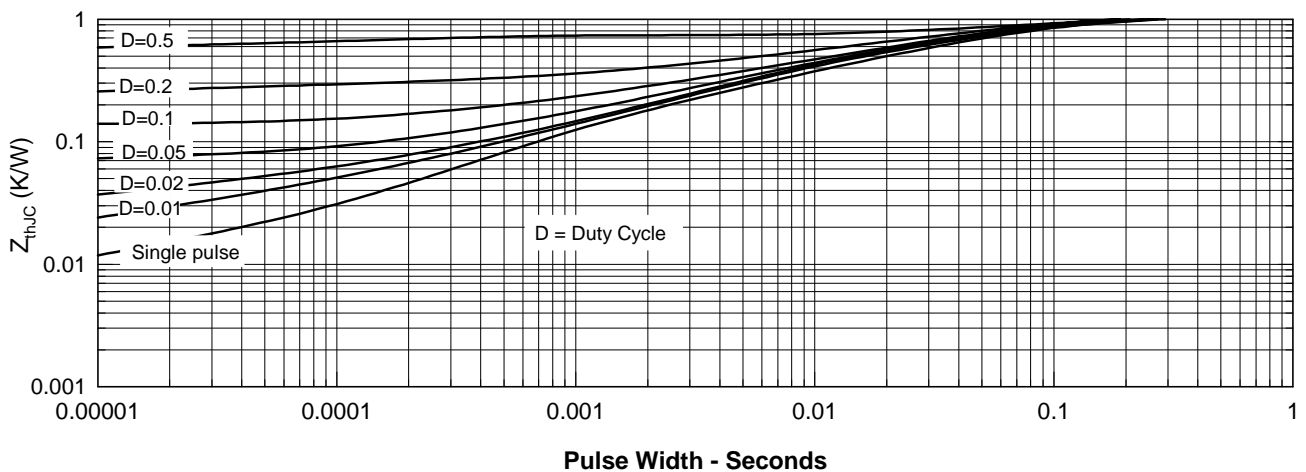


Figure 11. Transient Thermal Resistance